

PROGRAM

5th October

09.30

Registration

10.15

Welcome

1st Session

Plenary talk: Antonino Conte, STMicroelectronics, Italy
An 18nm ePCM NVM IP design for advanced microcontroller

applications

11.15

Plenary talk: Arnaud Furnemont, IMEC, Belgium

Memory opportunities in times of slow cost/bit scaling and fast compute efficiency improvement

12.00

Cristian Zambelli, University of Ferrara, Italy

Improving Solid State Drives Performance/Reliability: a cross layer approach

12.35

Lunch

2nd Session

14.00

Gabriel Molas, Weebit Nano Ltd, Grenoble, France

From Initial Concept to Market Adoption: Challenges and Outlook for Resistive Memories

14.35

Erika Covi, NaMLab, Dresden, Germany

Advancing Cognitive Systems: Harnessing the Power of Memristive Technology in CMOS Circuit Design

15.10

Konstantinos Konstantinou, Tampere University, Tampere,

The quest for defects in phase-change memory materials: structural and electronic aspects

15.45

Melika Payvand, University of Zurich and ETH Zurich,

Switzerland

Structure-function duality in memristive intelligent systems

16.20

Coffee break

6th October

3rd Session

9.30

Plenary talk: Alessandro Curioni, IBM Zurich, Switzerland

What's next in Computing: In-memory computing for next

generation AI acceleration

10.15

Plenary talk: Steve Pawlowski, Micron Technology, USA

The Rise of Memory Centric Computing Platforms

11.00

Coffe break

Kevin Garello, Spintec CEA, France

Spintronics: a solution for the future of embedded systems?

Carlo Ricciardi, Politecnico di Torino, Italy

Self-organized nanowire networks for neuromorphic computing and memory

encoding

O(n) Key-value Sort with Active Compute Memory

Petar Radojkovic, Barcelona Supercomputing Center, Spain

13.10

12.35

Lunch

More info available on the workshop website at www.iwcm2.eu

DIPARTIMENTO DI SCIENZA DEI MATERIALI







